

GMBTA14

NPN EPITAXIAL SILICON TRANSISTOR

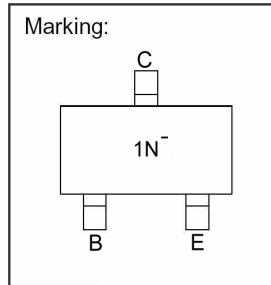
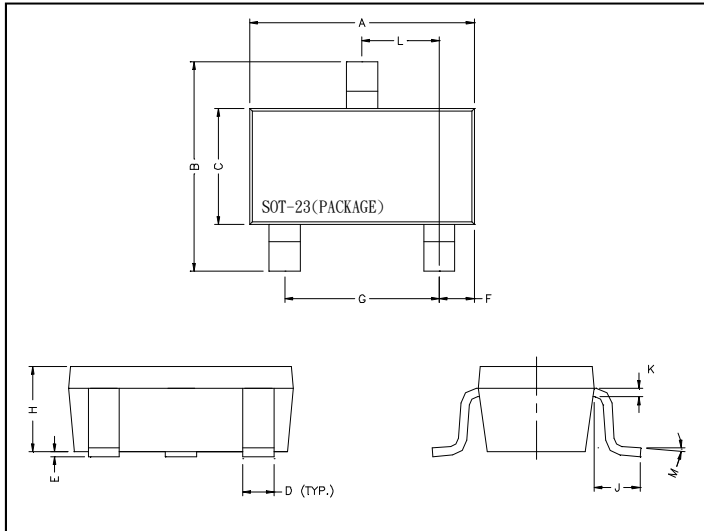
Description

The GMBTA14 is designed for Darlington Amplifier Transistor.

Features

- *High D.C. Current Gain
- *Collector-Emitter Voltage $V_{CES}=30V$

Package Dimensions



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	2.70	3.10	G	1.90	REF.
B	2.40	2.80	H	1.00	1.30
C	1.40	1.60	K	0.10	0.20
D	0.35	0.50	J	0.40	-
E	0	0.10	L	0.85	1.15
F	0.45	0.55	M	0°	10°

Absolute Maximum Ratings at $T_a = 25^\circ C$

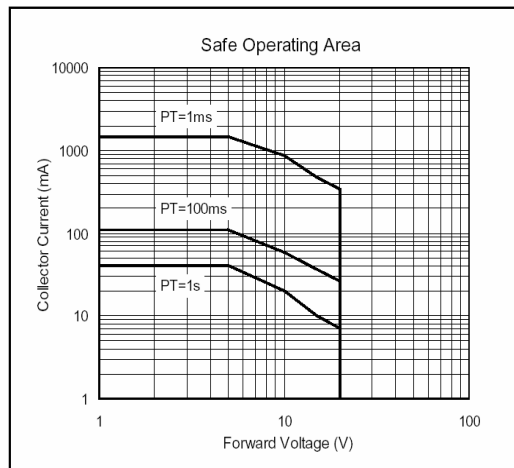
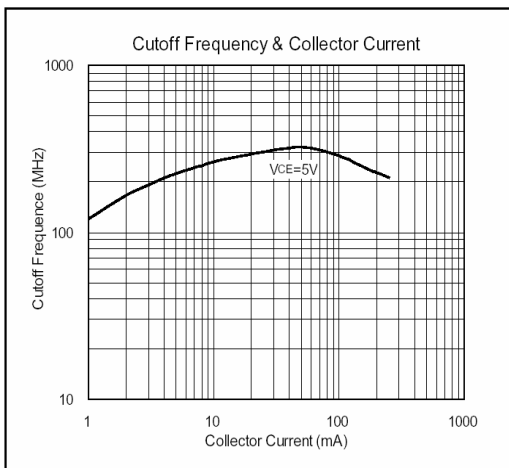
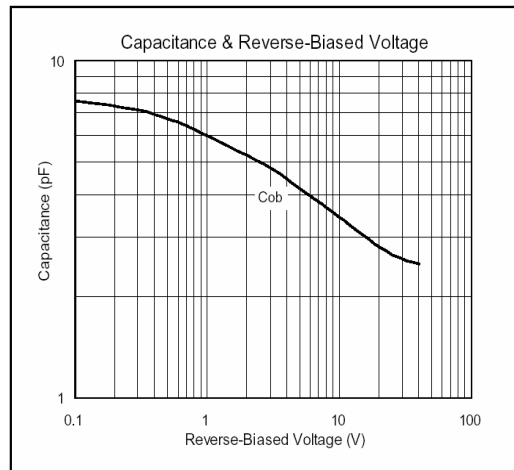
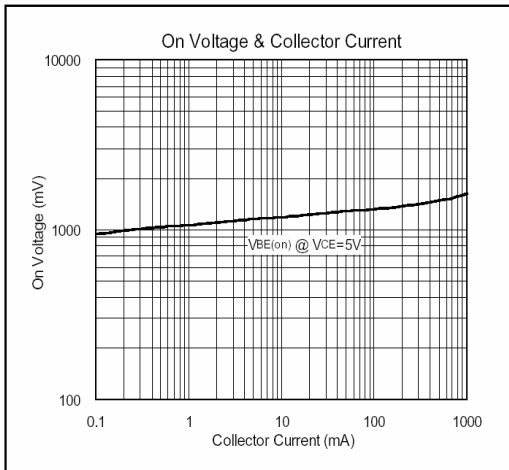
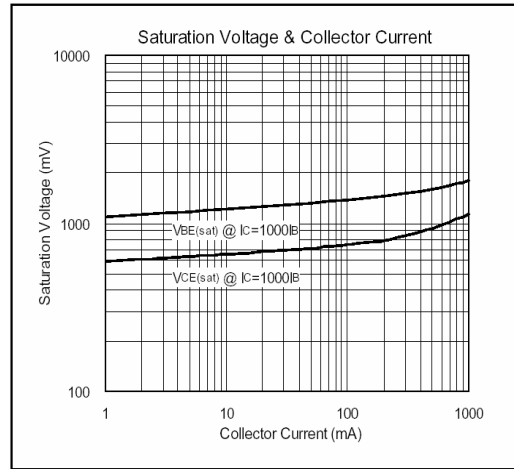
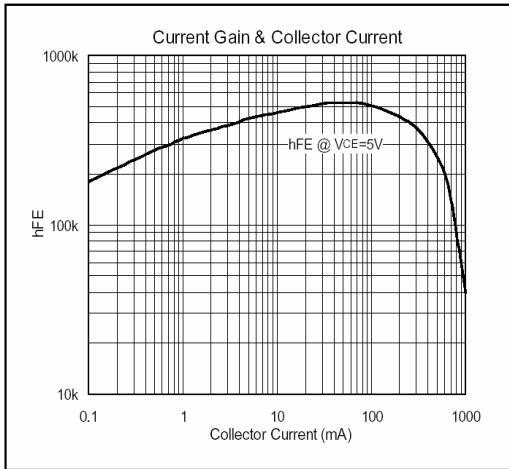
Parameter	Symbol	Ratings	Unit
Junction Temperature	T_j	+150	$^\circ C$
Storage Temperature	T_{stg}	-55 ~ +150	$^\circ C$
Collector to Base Voltage	V_{CB0}	30	V
Collector to Emitter Voltage	V_{CES}	30	V
Emitter to Base Voltage	V_{EBO}	10	V
Collector Current	I_c	500	mA
Total Power Dissipation	P_D	225	mW

Electrical Characteristics ($T_a = 25^\circ C$, unless otherwise noted)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
$V_{V_{CB0}}$	30	-	-	V	$I_c=100\mu A, I_E=0$
$V_{V_{CES}}$	30	-	-	V	$I_c=100\mu A, V_{BE}=0$
$V_{V_{EBO}}$	10	-	-	V	$I_E=10\mu A, I_c=0$
$I_{I_{CBO}}$	-	-	100	nA	$V_{CB}=30V, I_E=0$
$I_{I_{EBO}}$	-	-	100	nA	$V_{EB}=10V, I_c=0$
* $V_{V_{CE(sat)}}$	-	-	1.5	V	$I_c=100mA, I_B=0.1mA$
* $V_{V_{BE(on)}}$	-	-	2.0	V	$V_{CE}=5V, I_c=100mA$
* $h_{h_{FE1}}$	10k	-	-		$V_{CE}=5V, I_c=10mA$
* $h_{h_{FE2}}$	20k	-	-		$V_{CE}=5V, I_c=100mA$
f _T	125	-	-	MHz	$V_{CE}=5V, I_c=10mA, f=100MHz$
C _{ob}	-	-	6	pF	$V_{CB}=10V, I_E=0, f=1MHz$

Pulse Test: Pulse Width $\leq 380\mu s$, Duty Cycle $\leq 2\%$

Characteristics Curve



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